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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR μ PA1770

SWITCHING DUAL P-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The μ PA1770 is a P-channel MOS Field Effect Transistor designed for power management applications of portable machines.

ORDERING INFORMATION

PART NUMBER	PACKAGE
μPA1770G	Power SOP8

FEATURES

- · Dual chip type
- Low on-resistance

RDS(on)1 = 37 m Ω MAX. (Vgs = -4.5 V, ID = -3.0 A)

RDS(on)2 = 39 m Ω MAX. (VGS = -4.0 V, ID = -3.0 A)

 $R_{DS(on)3} = 59 \text{ m}\Omega \text{ MAX.} \text{ (Vgs} = -2.5 \text{ V, ID} = -3.0 \text{ A)}$

Low input capacitance

Ciss = 1300 pF TYP.

- Built-in G-S protection diode
- Small and surface mount package (Power SOP8)

ABSOLUTE MAXIMUM RATINGS (TA = 25°C, All terminals are connected.)

	Drain to Source Voltage	VDSS	-20	V
	Gate to Source Voltage	Vgss	∓12	V
	Drain Current (DC)	I _{D(DC)}	∓6.0	Α
	Drain Current (pulse) Note1	D(pulse)	∓24	Α
	Total Power Dissipation (1 unit) Note2	Рт	0.40	W
	Total Power Dissipation (2 unit) Note2	Рт	0.75	W
*	Total Power Dissipation (1 unit) Note3	Рт	1.7	W
*	Total Power Dissipation (2 unit) Note3	Рт	2.0	W
	Channel Temperature	Tch	150	°C
	Storage Temperature	Tstg	-55 to +150	°C

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1 %

- 2. Mounted on FR4 Board of 1600 mm² x 1.6 mm, Drain Pad size : 4.5 mm^2 x $35 \mu\text{m}$, T_A = $25 ^{\circ}$ C
- 3. Mounted on ceramic substrate of 1200 mm² x 2.2 mm, T_A = 25°C

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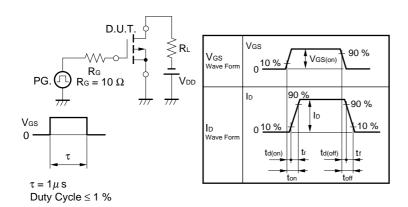
Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.



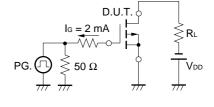
★ ELECTRICAL CHARACTERISTICS (TA = 25 °C, All terminals are connected.)

		•				
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	RDS(on)1	Vgs = -4.5 V, ID = -3.0 A		28	37	mΩ
	RDS(on)2	$V_{GS} = -4.0 \text{ V}, I_{D} = -3.0 \text{ A}$		29.5	39	mΩ
	RDS(on)3	$V_{GS} = -2.5 \text{ V}, I_{D} = -3.0 \text{ A}$		44	59	mΩ
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = -10 V, I _D = 1 mA	-0.5	-1.0	-1.5	٧
Forward Transfer Admittance	yfs	$V_{DS} = -10 \text{ V}, \text{ ID} = -3.0 \text{ A}$	5.0	11		S
Drain Leakage Current	loss	V _{DS} = -20 V, V _{GS} = 0 V			-1	μΑ
Gate to Source Leakage Current	lgss	$V_{GS} = \mp 12 V$, $V_{DS} = 0 V$			∓10	μΑ
Input Capacitance	Ciss	Vps = -10 V		1300		pF
Output Capacitance	Coss	Vgs = 0 V		325		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		155		pF
Turn-on Delay Time	td(on)	ID = -3.0 A		25		ns
Rise Time	tr	$V_{GS(on)} = -4.5 V$		110		ns
Turn-off Delay Time	td(off)	V _{DD} = −10 V		130		ns
Fall Time	tf	$R_G = 10 \Omega$		140		ns
Total Gate Charge	QG	ID = -6.0 A		11		nC
Gate to Source Charge	Qgs	V _{DD} = -16 V		2.0		nC
Gate to Drain Charge	Q _{GD}	Vgs = -4.5 V		4.0		nC
Body Diode Forward Voltage	V _F (S-D)	IF = 6.0 A, VGS = 0 V		0.8		V
Reverse Recovery Time	trr	IF = 6.0 A, VGS = 0 V		60		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A / μs		40		nC

TEST CIRCUIT 1 SWITCHING TIME



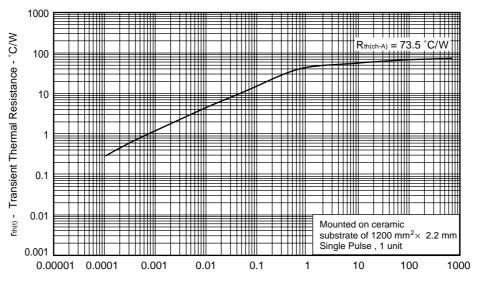
TEST CIRCUIT 2 GATE CHARGE





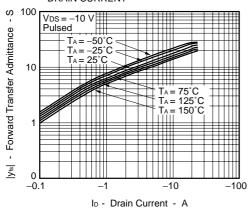
TYPICAL CHARACTERISTICS(TA = 25 °C, All terminals are connected.)



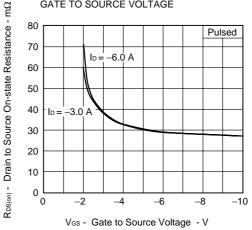


PW - Pulse Width - s

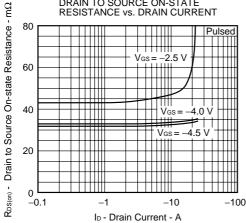
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



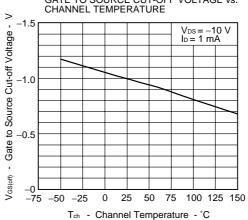
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



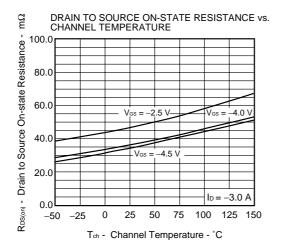
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

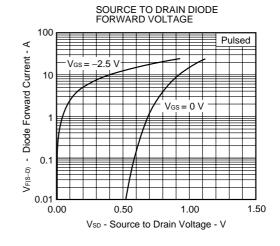


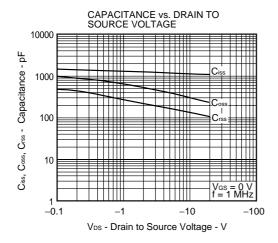
GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE

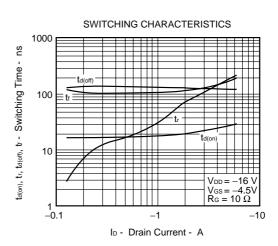


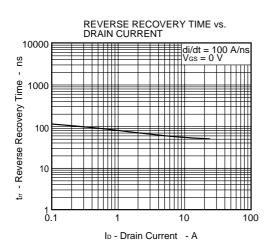
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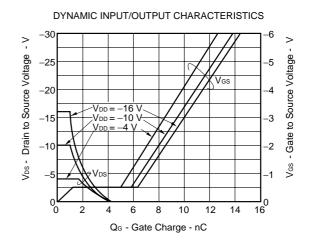


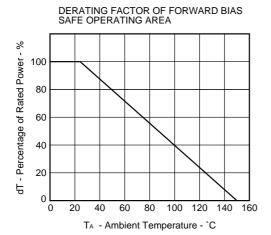


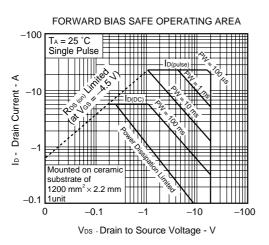


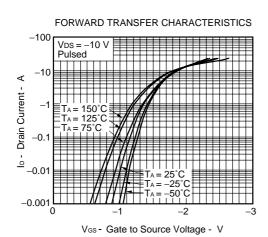


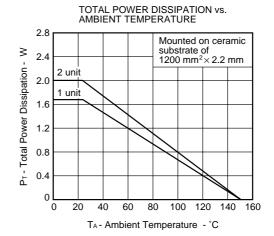


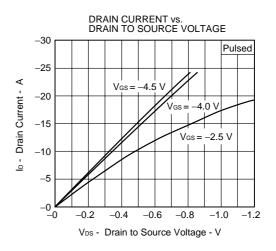










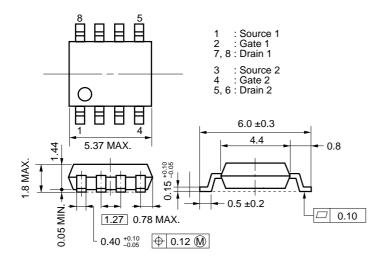


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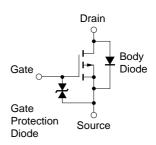
PACKAGE DRAWING (Unit: mm)

Power SOP8



EQUIVALENT CIRCUIT

(1/2 circuit)



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

NEC μ PA1770

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